

PRODUCT CHANGE NOTICE

PCN-2487 REV 1

| Notification Date: | Implementation Date: | Product Family: | Change Type: | PCN #: | | | | | | |
|--|--|---|---|-----------------------|--|--|--|--|--|--|
| October 7, 2020 | Janurary 7, 2021 | Analog | Fab, A/T Site, and Datasheet | 2487 | | | | | | |
| | TITLE | | | | | | | | | |
| Fab Porting from Glob | al Foundries to Magna | achip, Assembly & T | est Site Transfer, and I | Datasheet Change | | | | | | |
| | DES | CRIPTION OF CHANG | E | | | | | | | |
| As already announced technology wafer prod | | | ands, Singapore closed | their 0.35um | | | | | | |
| In order to assure con Semiconductor located | | | manufacturing to Magn echnology. | achip | | | | | | |
| transfer assembly and | l test to Greatek Electr ing Diodes logo (see F | onics Inc. in Miaoli, igure 1). For select | sure continuity of suppl Taiwan. Diodes is also products, the device da | changing the | | | | | | |
| Full electrical characte numbers. Refer to the | • | | en completed on repres mbedded in this file). | entative part | | | | | | |
| | | IMPACT | | | | | | | | |
| Continuity of Supply. | No impact to fit. | | | | | | | | | |
| | PF | RODUCTS AFFECTED | | | | | | | | |
| Table 1 - Fab Porting | (Global Foundry to Ma | gnachip) and New A | A/T Site (Greatek) | | | | | | | |
| Table 2 - Fab Porting | (Global Foundry to Ma | gnachip) and Updat | ted Datasheet (IDD) | | | | | | | |
| Table 3 - Fab Porting (IDD) | Global Foundry to Ma | gnachip), New A/T | Site (Greatek) and Upd | ated Datasheet | | | | | | |
| | | WEB LINKS | | | | | | | | |
| Manufacturer's Notice: | https://www.c | liodes.com/quality/produ | <u>ict-change-notices/diodes-pr</u> | oduct-change-notices/ | | | | | | |
| For More Information Cor | ntact: <u>http://www.di</u> | odes.com/contacts.html | | | | | | | | |
| Data Sheet: | http://www.di | odes.com/catalog | | | | | | | | |
| | | DISCLAIMER | | | | | | | | |
| Unless a Diodes Incorpor all changes described in | | | g within 30 days of the pos | sting of this notice, | | | | | | |



| Table 1 - Fab Porting (Global Foundry to Magnachip) and New A/T Site (Greatek) | | | | |
|--|----------------|--|--|--|
| PI6C20400BHEX | PI6C557-03ALEX | | | |

| Table 2 - Fab Porting (Global Foundry to Magnachip) and Updated Datasheet (IDD) (see Figure 2 and Figure 3 for datasheet update) | | | | | |
|---|---------------|----------------|--|--|--|
| PI6C557-03LEX | PI6C557-05BLE | PI6C557-05BLEX | | | |

| Table 3 - Fab Porting (Global Foundry to Magnachip), New A/T Site (Greatek) and Updated Datasheet (IDD) (see Figure 3 for datasheet update) | | | | |
|---|--|--|--|--|
| PI6C557-05LEX | | | | |

Figure 1. Marking Change

| Old marking | New marking |
|--|--|
| $ \begin{array}{c} $ | PI6C DII 20400BHE YYYWWXX Y: Die Rev |
| WW: Work Week 1st X: Assembly Code 2nd X: Fab Code Bar above fab code means Cu wire | YY: Year WW: Work Week 1st X: Assembly Code 2nd X: Fab Code Bar above fab code means Cu wire |



Figure 2: PI6C557-03LEX IDD Datasheet Update

Before

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|-------------------|------------------|-----------------------------|------|------|------|------|
| I _{DD} | Operating Supply | $R_L = 50\Omega, C_L = 2pF$ | | | 65 | mA |
| I _{DDOE} | Current | OE = LOW | | | 35 | mA |

After

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|-------------------|------------------|-----------------------------|------|------|------|------|
| I _{DD} | Operating Supply | $R_L = 50\Omega, C_L = 2pF$ | | | 95 | mA |
| I _{DDOE} | Current | OE = LOW | | | 50 | mA |

Figure 3: PI6C557-05BLE, PI6C557-05BLEX and PI6C557-05LEX IDD Update

Before

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|-------------------|-----------------------|-------------------------------------|------|------|------|------|
| I _{DD} | Operating Supply Cur- | $R_L = 50\Omega, C_L = 2pF @100MHz$ | | 105 | 120 | mA |
| I _{DDOE} | rent | OE = LOW | | 40 | 50 | mA |

After

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|-------------------|-----------------------|-------------------------------------|------|------|------|------|
| I _{DD} | Operating Supply Cur- | $R_L = 50\Omega, C_L = 2pF @100MHz$ | | 105 | 130 | mA |
| I _{DDOE} | rent | OE = LOW | | 40 | 50 | mA |